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Spin-based optical quantum gates via Pauli blocking in semiconductor quantum dots

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Abstract

We present a solid-state implementation of ultrafast conditional quantum gates. Our proposal for a quantum-computing device is based on the spin degrees of freedom of electrons confined in semiconductor quantum dots, thus benefiting from relatively long decoherence times. More specifically, combining Pauli blocking effects with properly tailored ultrafast laser pulses, we are able to obtain sub-picosecond spin-dependent switching of the Coulomb interaction, which is the essence of our conditional phase-gate proposal. This allows us to realize *a fast two qubit gate which does not translate into fast decoherence times* and paves the road for an all-optical spin-based quantum computer.

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Recent advances in quantum-information science [1] have led to a number of schemes for implementing quantum information processing (QIP) devices. Several theoretical proposals have been made and admirable experimental progress has been made in quantum optics [2,3], NMR [4], and solid state proposals including Josephson junctions and quantum dots [5–11]. Quantum dot (QD) implementation schemes based on the electronic spin degrees of freedom [6,7] are characterized by relatively long decoherence times, compared to charge excitations [8], which on the other hand provide much stronger interactions and thus faster gate operation.

Below we propose a novel implementation scheme for the realization of a fast two-qubit gate which does not translate into fast decoherence time. While our qubit is the spin of an excess electron in a QD, the two-qubit gate relies on interaction between excitons. Thus we merge ideas from both the fields of spintronics and optoelectronics: using spin as quantum memory, and charge for the interaction between qubits, we can benefit (i) from the "low" spin decoherence rates of conduction electrons in III-V semiconductors [12], and (ii) from ultrafast (sub-picosecond) optical gating of charge excitations. Combination with innovative schemes for all optical coherent control of the electron spin [7,13] sets the stage for an all optical spin-based QIP.

We consider an excess electron in a semiconductor QD, its spin degrees of freedom defining the qubit $|0\rangle$, $|1\rangle$. Our quantum register consists of an array of GaAs-based QDs each dot containing one excess conduction electron [6]. Single-qubit operations can be done optically [7,13] or on a pico-second time scale by employing g-factor modulated materials or time-dependent magnetic fields [6]. The key ingredient in any quantum computation scheme is the two qubit gate, that together with single qubit operations forms a universal set of gates [14].

We aim at implementing a two-qubit phase gate, defined through the truth table $|\alpha\rangle \otimes |\beta\rangle \rightarrow e^{\imath\alpha\beta\theta}|\alpha\rangle \otimes |\beta\rangle$ where $\alpha, \beta \in \{0, 1\}$. The dynamics required to perform the gate operation exploits a *Pauli-blocking* mechanism, as observed experimentally in QDs [15,16]. We assume that the QDs can be individually addressed via laser excitation, using, e.g.,

near-field techniques [7] or energy-selective addressing of QDs [8]. The control of the phase accumulated by Coulomb interactions is obtained in the following way: by shining a σ^+ polarized laser pulse on the QD, due to the Pauli exclusion principle a $|M_J^e = -1/2, M_J^h = +3/2\rangle$ electron-heavy hole pair is created in the s-shell only if the excess electron — already present in the QD — has a spin projection 1/2. Thus with a π-pulse we obtain an exciton conditional to the spin state (qubit)

$$\alpha|0\rangle + \beta|1\rangle \rightarrow \alpha|0\rangle + \beta|x^-\rangle, \tag{1}$$

where the logical states $|0\rangle$ and $|1\rangle$ shall be defined below, and the charged exciton state $|x^-\rangle$ plays the role of an auxiliary state needed to obtain the desired phase. In this way one obtains precise spin control of the switching on (and off) of further Coulomb interactions. In particular, this allows the switching on of exciton-exciton interactions on neighboring quantum dots conditional to the spins (qubits) being in state $|1\rangle \otimes |1\rangle$. We emphasize that the presence of the photo-generated electron-hole pair is only required during the gating, after which the latter will be annihilated via a second laser pulse. Thus excitonic interactions can be switched on and off, in contrast to proposals where qubits are stored in excitonic states [8].

For a quantitative description, we consider the Hamiltonian of two interacting QDs $H = \sum_\nu H_\nu + H_{ab} + \sum_\nu H_\nu^{\rm int}$, where the index ν runs over the QD label a, b [17]. The single-QD Hamiltonian is $H_\nu = H_\nu^c + H_\nu^{cc}$, where the term describing the noninteracting dynamics of the electrons and holes confined within the QDs is $H_\nu^c = \sum_{i,\sigma=\pm 1/2} \epsilon_{i,\sigma}^e c_{\nu,i,\sigma}^\dagger c_{\nu,i,\sigma} + \sum_{j,\sigma'=\pm 3/2} \epsilon_{j,\sigma'}^h d_{\nu,j,\sigma'}^\dagger d_{\nu,j,\sigma'}$, and subscripts i and j denote single-particle states — e.g., $c_{\nu,i,\sigma}^\dagger$ ($d_{\nu,i,\sigma}^\dagger$) is a creation operator for a conduction band electron (hole) in the i-th single particle state of QD ν, with spin projection σ. The Coulomb-interaction part of the Hamiltonian H_ν^{cc} is then composed of three terms: electron-electron, electron-hole, and hole-hole interactions. The coupling of the carrier system with a classical light field is $H_\nu^{\rm int} = -\sum_{ij} \left[\mu_{ij}^{eh} E^*(t) e^{-\imath\omega_L t} c_{\nu,i,-1/2}^\dagger d_{\nu,j,3/2}^\dagger + h.c.\right]$, where $E(t)$ is a σ^+ circularly polarized high frequency laser field, with a central frequency ω_L, and μ_{ij}^{eh} denotes the dipole matrix

element between the electron and hole wave functions.

An idealized model for two neighboring QDs is obtained by considering dynamics restricted to the Hilbert space of relevant states, which are the two spin states of the ground-state excess electron $|0\rangle_\nu$, $|1\rangle_\nu$ representing the qubit, and the auxiliary excitonic quantum states $|x^-\rangle_\nu$ ($\nu = a, b$). These states are defined as eigenstates of the single dot Hamiltonians H_ν. In a single-particle picture these states are approximated by $|0\rangle_\nu \equiv c^\dagger_{\nu,0,-1/2}|\text{vac}\rangle$, $|1\rangle_\nu \equiv c^\dagger_{\nu,0,1/2}|\text{vac}\rangle$, and $|x^-\rangle_\nu \equiv c^\dagger_{\nu,0,1/2}c^\dagger_{\nu,0,-1/2}d^\dagger_{\nu,0,3/2}|\text{vac}\rangle$, while $|\text{vac}\rangle$ stands for the electron-hole vacuum, i.e., the crystal ground state [8,18].

Our goal is now to design a process which starts from a superposition of the qubit states, populates the auxiliary excitonic states $|x^-\rangle$, and afterwards returns back to the qubit space, achieving a phase gate. In the idealized model outlined above, due to Pauli blocking, an exciton is obtained via a σ^+-polarized laser pulse only if the excess electron is in state $|1\rangle$ (see Fig. 1). The presence of an exciton in both QDs induces the so-called biexcitonic shift ΔE_{ab} [8], which is defined as the difference between the exciton binding energy in the presence or absence of a second exciton in the neighboring QD. In this context, the most straightforward gating strategy would be the following [19]: (i) apply an exciting pulse to both QDs; (ii) wait for a time $\Delta t \propto \theta/\Delta E_{ab}$, for the phase θ to be accumulated, and (iii) bring the QDs to their original state by a de-exciting pulse. In this way the dipole-dipole interaction is active only if the excess electrons in both QDs are in state $|1\rangle$ (see Fig. 2), giving the desired state-dependence of the two-qubit phase. The typical time scale τ for a gate can be no shorter than the inverse of the biexcitonic shift, which is of the order of 1 ps [8].

The strongest decoherence source in charge-based gating schemes is charge-phonon interaction. Recent single dot photoluminescence spectroscopy experiments [24] have measured ground state excitonic phonon dephasing times of almost 1 ns, i.e. limited only by the excitonic lifetime. Theoretical studies of pure dephasing in small quantum dots [25] have shown that this apparent absence of dephasing is due to polaronic effects which are manifested in the presence in the spectra of a sharp zero-phonon line, and that the leading

dephasing mechanism is the coupling to acoustic phonons through the deformation potential. The polaron formation time t_0 associated to this mechanism is of the order of few picoseconds. In order to take full advantage of the large strength of the zero phonon line calculated in [25], gating schemes based on charged states in QDs, could then be performed adiabatically with respect to t_0. In this way gating would be performed among dressed long-lived quasi-particles (polarons) representing the quasi-eigenstates of the total Hamiltonian. A technological condition to be taken into account is that, since the needed laser pulses are strongly energy selective (their typical energy uncertainty is of $\sim$ 0.1meV), a precise knowledge of the characteristics of the QDs involved in the gate would be required. An important point to be stressed is that, due to the strong confinement regime, the typical energy associated to a phonon is much smaller than the typical electron or hole intra-band level spacing ($\sim$ 25 meV), so that the coupling to phonons will not induce a significant level renormalization and, in particular, will not induce substantial mixing between different electronic (hole) states. The relevant polaron states would then be well approximated by the product between the ground electron (hole) state and a linear superposition of all the relevant phonon states [25]. This fact would allow us still to label each polaron with the corresponding electron (hole) spin, i.e. it would still be possible to apply, even to the dressed particles, a Pauli-blocking based scheme.

Taking into account mixing between the heavy- and the light-hole subbands, the eigenstate of the hole involved in our gate process has to include a correction, weighted by the small parameter ε, and becomes $\propto \varepsilon d^\dagger_{0,1/2}\left|\text{vac}\right\rangle + d^\dagger_{0,3/2}\left|\text{vac}\right\rangle$. This will lead to a weak violation of the selection rules for laser coupling, since a σ^+-polarized laser in this case will not only excite the desired transition $|1\rangle \rightarrow |x^-\rangle$ with Rabi frequency Ω, but also the unwanted one $|0\rangle \rightarrow |x^+\rangle \equiv c^\dagger_{0,-1/2}c^\dagger_{0,1/2}d^\dagger_{0,1/2}\left|\text{vac}\right\rangle$ with Rabi frequency $\varepsilon\Omega$. Such an undesired exciton admixture for the qubit in state $|0\rangle$ can be as big as 10%. However, with an adiabatic procedure involving a detuned laser pulse, we can guarantee that this exciton population can be returned to zero after the laser pulses, while the needed phase difference between the computational basis states can still be obtained. Indeed, assuming nonzero detuning,

states $|0\rangle$ and $|1\rangle$ are adiabatically connected to dressed states having different excitonic components. Therefore each two-qubit computational basis state $|\alpha\beta\rangle$ (where $\alpha, \beta \in \{0, 1\}$) will still acquire, after the gate process, a different phase $\phi_{\alpha\beta}$. Irrelevant single-qubit contributions to the phase can be straightforwardly undone via single-qubit rotations, recovering the transformation $|\alpha\beta\rangle \to e^{\imath\alpha\beta\theta}|\alpha\beta\rangle$, with the gate phase given by $\theta \equiv \phi_{00} + \phi_{11} - \phi_{01} - \phi_{10}$. In order to implement a universal set of quantum gates, $\theta \neq 0$ has to be obtained. To check whether this can be achieved in a realistic situation, we need a model for the two-QD dynamics including hole mixing. As anticipated above, the laser is assumed to be detuned by a frequency Δ from the exciton transition. In a rotating wave approximation the effective Hamiltonian after eliminating the time dependence becomes

$$\begin{aligned} H_{\text{eff}} = & \sum_{\nu=a,b} \left[\frac{1}{2}\hbar\Omega(t) \left(|1\rangle_\nu\langle x^-| + \varepsilon|0\rangle_\nu\langle x^+| \right) + \text{h.c.} \right] \\ & - \Delta \sum_{\nu=a,b;\sigma=+,-} |x^\sigma\rangle_\nu\langle x^\sigma| \\ & + \Delta E_{ab} \sum_{\sigma,\sigma'=+,-} |x^\sigma\rangle_a\langle x^\sigma| \otimes |x^{\sigma'}\rangle_b\langle x^{\sigma'}|, \end{aligned} \tag{2}$$

where $\Omega(t) = 2\mu^{eh}E(t)/\hbar$ denotes the Rabi frequency. As long as the Rabi frequency Ω, the biexcitonic shift ΔE_{ab} and the inverse pulse duration time scale $\hbar\tau^{-1}$ are much smaller than the QD level spacing $\Delta\epsilon \equiv \epsilon_1^e - \epsilon_0^e$, transitions to excited states are negligible. Since our QDs are assumed to be in the "strong-confinement regime", these conditions can be very well satisfied. Typical experimental parameters employed in the calculations below assume a width of the QDs (in the growth direction) as well as the inter-dot barrier width of 50Å and a typical level spacing of $\Delta\epsilon \approx 25\,\text{meV}$. By controlling the external in-plane electric field [8], one is able to adjust the electrical dipole of the exciton which effects the biexcitonic shift: for an electric field $F = 70\,\text{kV/cm}$, the biexcitonic shift is $\Delta E_{ab} \approx 3\,\text{meV}$ [8].

The procedure we have in mind is as follows: We prepare our system in a superposition of the logical states $|0\rangle$ and $|1\rangle$, and we switch on adiabatically a laser with detuning Δ from the excitonic transition. We want to follow adiabatically the dressed energy levels of the system, up to a point in which the ratio $\Delta/\Omega(t)$ becomes of the order of unity or smaller. If we do so, the state $|1\rangle$ evolves into an adiabatic eigenstate with a bigger excitonic component

than the one that is reached starting from $|0\rangle$. Then we switch the laser adiabatically off. If we consider two quantum dots, this mechanism will let different two-qubit computational basis states acquire a different phase even in the presence of hole mixing. However, we must make sure that at the end of gate operation no population is left in the excitonic states. We can expect that this be the case as long as adiabaticity is satisfied. To check this with a numerical simulation, we chose a Gaussian Rabi frequency pulse shape $\Omega(t) = \Omega_0 e^{-(t/\tau)^2}$ in the Hamiltonian Eq. (2). The adiabaticity condition takes then the form $\Omega_0 \tau \gg 1$. To this we must add the condition $\tau \gg t_0$, as discussed above, in order to allow for the formation of long-lived polaron states. The latter condition turns out to be more stringent, since the previous one can in principle be satisfied also for τ of the order of picoseconds, by just increasing the Rabi frequency

Assuming a biexcitonic shift $\Delta E_{ab} = 3$ meV, a detuning $\Delta = \Delta E_{ab}$, a pulse width $\tau = 10$ ps and a peak Rabi frequency $\hbar\Omega_0 \approx 5.9$ meV, we can obtain the desired value $\theta = \pi$ while the population eventually left in the unwanted (single- and bi-) exciton states remains of the order of 10^{-7}. Results of the simulation are shown in Fig. 3. This scheme has the advantage of using the same pulse to excite both QDs, thus relieving us from the need to tailor different pulses to address the two QDs.

The fidelity of the described gate will be limited by deviations from the idealized model (2), and decoherence due to coupling to the environment, leading to energy relaxation, exciton dephasing, spin decoherence [21,22]. First, population leakage to other, e.g., excited states by the laser is negligible for the present parameters since, as discussed above, $\tau\Delta\epsilon/\hbar \gg 1$. Hopping of the exciton [20] between the QDs involved in the gate is not allowed by spin selection rules, and should be negligible to other QDs due to energy conservation arguments. Typical spin decoherence times are of the order of $\sim 0.1 \div 1$ microseconds [6,7], and exciton lifetimes in the ground state are given by the radiative life time of the order of nanoseconds, while our gate can be performed on a few-ps time scale. The probability for field ionization of the extra electron in the QD ground state is proportional to the ratio between the Stark shift $(eF)^2/m\omega_e^2$ and the height of the potential well in the in-plane direction. Such a process

should be negligible for the present parameters. Dephasing due to coupling of the electrons to the nuclear spin can be suppressed by applying a further external magnetic field [23]. For the simulations of Fig. 3 we have included decoherence processes by employing a standard $T1 - T2$ model, assuming a dephasing time of 1 ns.

A quantum computer requires reading out the state of the qubit (see, e.g., [26]. This can be achieved easily by adapting the familiar quantum jump technique from quantum optics employing again the Pauli-blocking mechanism [2]. We emphasize that the same optical coupling to excitons provides a mean to swap the spin-qubit to a photonic qubit by radiative emission into a cavity, thus providing a natural optical interconnect between spins as quantum memory and photonic qubits for quantum communications [27].

In summary, we have proposed a two-qubit phase gate which benefits from the vast time-scale separation between excitonic and spin dephasing processes. Whereas our proposed qubit is given by the spin of a conduction electron and thus decoheres on a micro-second time scale, our conditional two-qubit phase gate is driven/controlled by Coulomb interaction on a picosecond time-scale. The ratio between gate operation time and the coherence time of the quantum memory is therefore of the order of 10^5. Moreover, since our scheme employs the long-range characteristics of Coulomb interactions, gating can be performed between non-neighboring qubits. We demonstrated that our scheme tolerates a significant amount of hole mixing (i.e., of violation of the Pauli-blocking selection rules), under realistic parameter conditions. Further improvement is expected from a more detailed engineering of the decoherence sources, and this will be the subject of future investigations.

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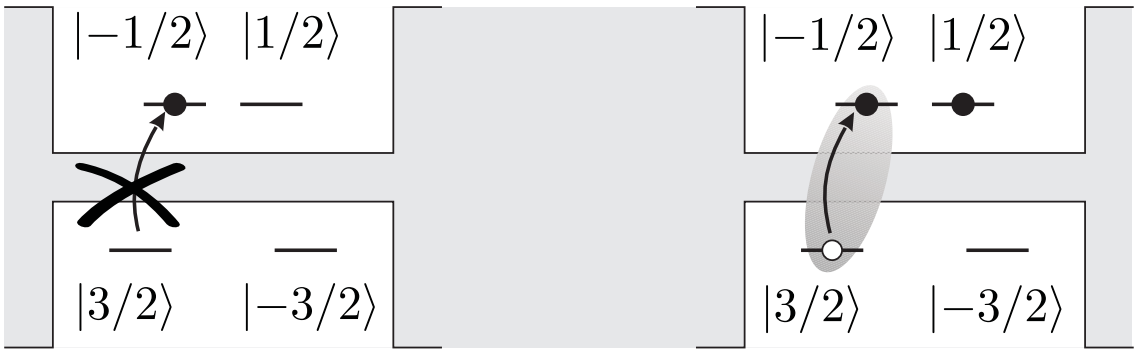
FIGURES

FIG. 1. Quantum dots and energy level scheme. Left: the excess electron is in state $|-1/2\rangle \equiv |0\rangle$ and the transition induced by a σ^+-polarized light is blocked. Right: the excess electron is in $|+1/2\rangle \equiv |1\rangle$ and the exciton can be excited.

FIG. 2. Dynamics of the two-qubit gate for the computational basis states $|\alpha\rangle_a \otimes |\beta\rangle_b$ ($\alpha, \beta \in \{0, 1\}$). In the ideal case of perfect Pauli blocking, the dipole-dipole interaction is present only for the $|11\rangle$ component.

FIG. 3. Upper panel: Biexcitonic population obtained starting from an initial state $|00\rangle$ (short-dashed line), $|01\rangle$ or $|10\rangle$ (solid line), and $|11\rangle$ (long-dashed line). Lower panel: Pulse shape and accumulated phase.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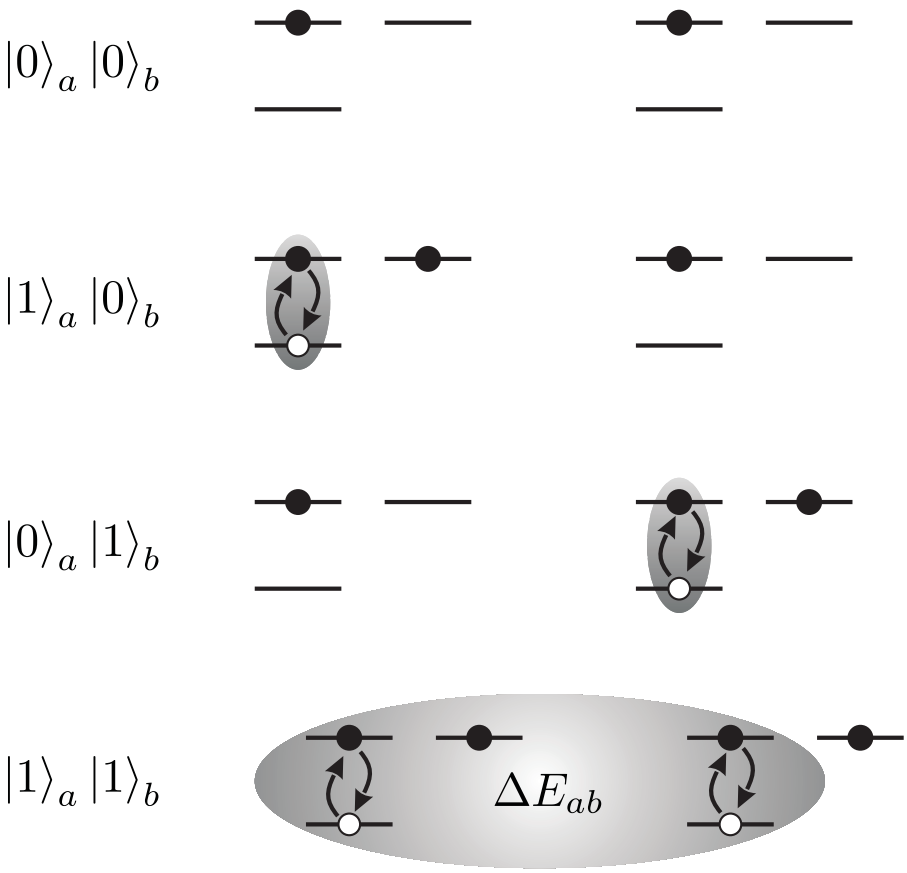
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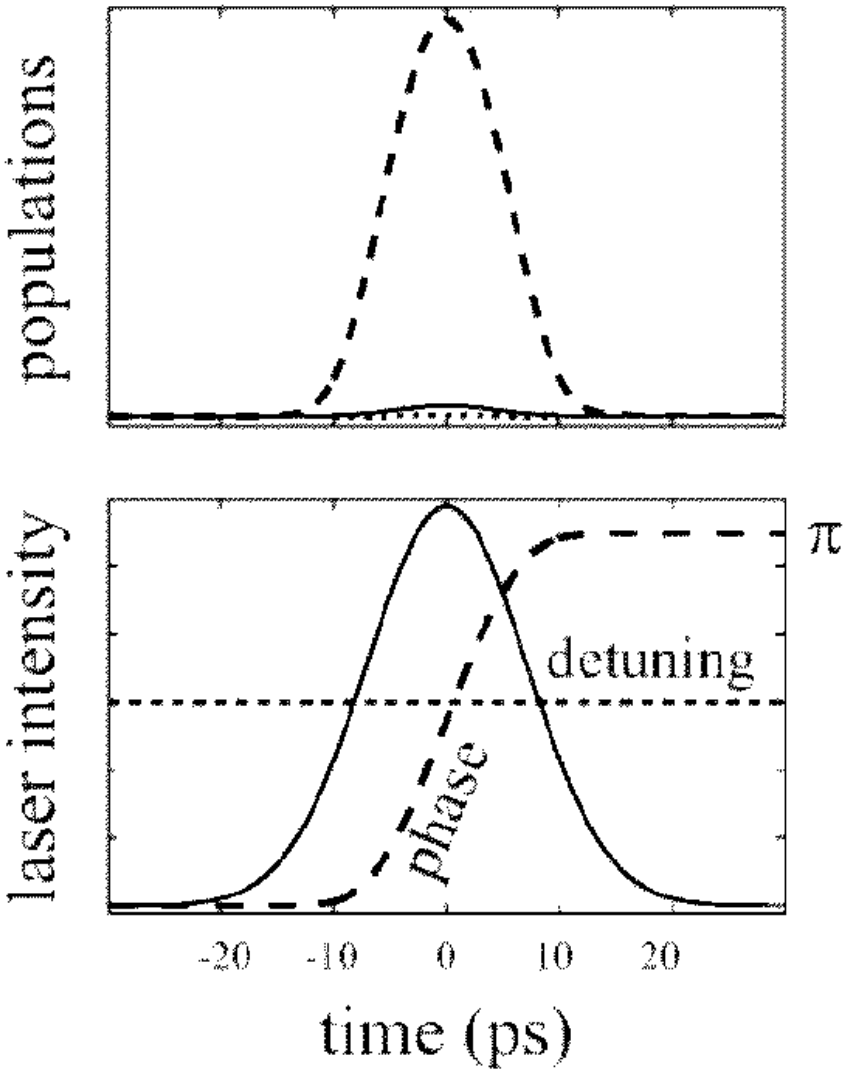
ΔE_{ab}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